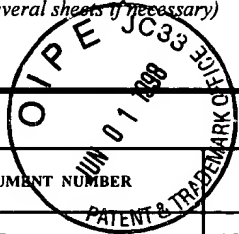


<b>INFORMATION DISCLOSURE CITATION</b> (Use several sheets if necessary)	Docket Number (Optional) <b>11675.23</b>	Application Number <b>09/031,617</b>
Applicant(s) <b>Cathey, et al.</b>		
Filing Date <b>2/27/98</b>		Group Art Unit



U.S. PATENT DOCUMENTS							
EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
JP	1	5,069,747	12/3/91	Cathey, et al.	156	643	12/21/90

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FOREIGN PATENT DOCUMENTS								
	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO
		NONE						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)		
JP	2	Verhaar, et al., "A 25 um Bulk Fill CMOS SRAM Cell Technology With Fully Overlapping Contacts," IEDM Technical Digest, pp. 473-476, International Electron Devices Meeting, San Francisco, CA December 9-12, 1990.

EXAMINER <i>James Park</i>	DATE CONSIDERED <b>11-12-99</b>
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.